

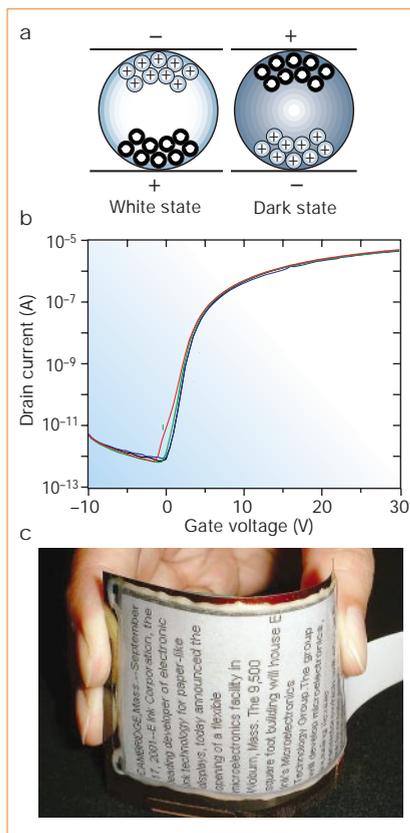
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Electronic paper

## Flexible active-matrix electronic ink display

Ultrathin, flexible electronic displays that look like print on paper are of great interest<sup>1–4</sup> for application in wearable computer screens, electronic newspapers and smart identity cards. Here we realize the fabrication of such a display on a bendable active-matrix-array sheet. The display is less than 0.3 mm thick, has high pixel density (160 pixels × 240 pixels) and resolution (96 pixels per inch), and can be bent to a radius of curvature of 1.5 cm



**Figure 1** Flexible active-matrix electronic-ink displays. **a**, Operating principle of electronic ink. The relative movement of negatively charged black and positively charged white particles inside their microcapsules is controlled by the direction of the applied voltage. **b**, A backplane thin-film transistor measured *in situ* under compressive stress. The transistor is bent to three different radii of curvature: green, 2.0 cm (0.19% strain); blue, 1.3 cm (0.29% strain); and red, 1.0 cm (0.38% strain). The thin-film transistor has identical characteristics when measured without bending (black curve) and at a radius of curvature of 2.0 cm; degradation is minimal even at 1.0 cm. Results were similar under tensile stress. **c**, Text image shown on a bent display whose resolution is 96 d.p.i. and which has a white-state reflectance of 43% and a contrast ratio of 8.5:1.

without any degradation in contrast. This use of electronic ink technology on such an ultrathin, flexible substrate should greatly extend the range of display applications.

Thin (0.4-mm) but inflexible liquid-crystal displays have been made on plastic by using a diode-matrix array<sup>5</sup> and an amorphous-silicon, thin-film transistor (TFT), active-matrix array<sup>6</sup>. To create a flexible display, we used a TFT array (backplane) with microencapsulated electrophoretic material (electronic ink)<sup>7</sup>, which consists of millions of microcapsules containing charged pigment particles in a clear fluid. A negative voltage applied to the top surface causes the positive white particles to move to the top of the capsule and the surface to appear white; reversing the electric field causes the negative black particles to appear at the top surface and create a dark spot (Fig. 1a).

We used a 75- $\mu\text{m}$ -thick steel-foil substrate to build the TFT backplane because steel foil is lightweight, mechanically stable and compatible with existing fabrication processes for active-matrix liquid-crystal displays<sup>8,9</sup>. Before the array fabrication, an insulating layer was applied onto the foil to render the substrate passive. The amorphous-silicon TFTs were made in the bottom-gate, back-channel etch configuration. The gate and source/drain metal were deposited by sputtering. A ductile composite of aluminium and refractory metal was used for the gate metal to enhance the backplane's flexibility.

Silicon nitride, amorphous silicon and a doped amorphous-silicon layer were deposited as the gate insulator, the channel and the contact layer, respectively, by plasma-enhanced chemical-vapour deposition. The metal, semiconductor and insulator layers were patterned by photolithography. The display was made by laminating a sheet of electronic ink onto the backplane. The electronic ink consists of a layer of electrophoretic microcapsules and a polymer binder, coated onto a polyester/indium-tin oxide (common electrode) sheet. The total display thickness is less than 0.3 mm.

A typical TFT has a threshold voltage of 4.0 volts and a linear mobility of 0.50 cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup>. The drain off current is about 1.0 pA at 10 V drain voltage. The current on/off ratio is 5 × 10<sup>6</sup>, which is sufficient for high-resolution displays. The TFT performance does not degrade after first being bent for 120 seconds around a cylinder that is 2 mm in radius (1.9% strain) and then released.

We also measured TFTs *in situ* under compressive stress at three radii of curva-

ture (Fig. 1b). Because steel has a large Young's modulus, our selection of a thin substrate decreases the distance of the TFT circuit from the display neutral plane<sup>10</sup>, reducing the in-plane strain of the circuit. As a result, the display can be repeatedly bent 20 times to a radius of curvature of 1.5 cm without any degradation.

Bias temperature stress on the TFT backplane was performed at a gate voltage of 25 V and up to 80 °C. The results indicate that the flexible backplane has a threshold voltage shift comparable to that of conventional glass TFT backplanes in laptop computers, and possibly a similar reliability and lifetime. The row electrode is driven between 0 and 24 V, and the column electrode is driven between 0 and 20 V.

Figure 1c shows the bent display of a text image of 96 d.p.i. resolution; the display has a viewing angle of almost 180°. The ink-switching speed is 250 ms, which is sufficient for electronic paper. For wearable computers, a reduction to 15 ms would be required for video-rate switching; in addition, the substrate thickness would need to be reduced for foldable displays. We suggest that electronic ink combined with flexible amorphous-silicon active-matrix backplanes will provide a viable pathway to 'e-paper' and wearable computer screens.

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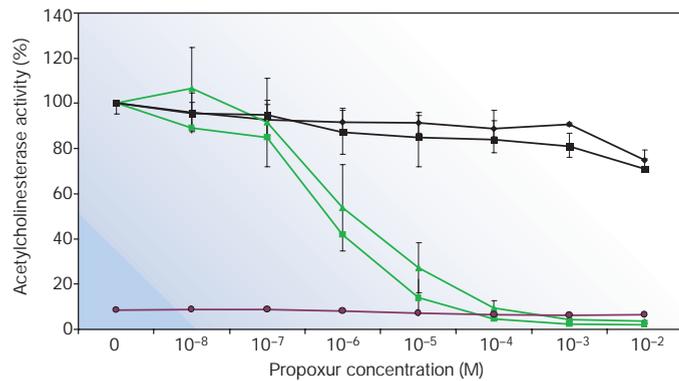
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Comparative genomics

## Insecticide resistance in mosquito vectors

Resistance to insecticides among mosquitoes that act as vectors for malaria (*Anopheles gambiae*) and West Nile virus (*Culex pipiens*) emerged more than 25 years ago in Africa, America and Europe; this resistance is frequently due to a loss of sensitivity of the insect's acetylcholinesterase enzyme to organophosphates and



**Figure 1** Residual acetylcholinesterase activity of susceptible (green squares) and resistant (black diamonds) mosquitoes assayed in homogenates and lysates from transfected S2 cells in the presence of increasing concentrations of the carbamate insecticide Propoxur. S2 cells were transfected with the recombinant pAc5.1/V5-His vector (Invitrogen) either alone (purple circles) or with expression of either sensitive acetylcholinesterase-1 (green triangles) or insensitive G119S-mutant enzyme (black squares). Residual enzyme activity was assayed after incubation with Propoxur for 15 min (ref. 5). Three independent experiments were carried out using different volumes of cell lysate.

carbamates<sup>1</sup>. Here we show that this insensitivity results from a single amino-acid substitution in the enzyme, which we found in ten highly resistant strains of *C. pipiens* from tropical (Africa and Caribbean) and temperate (Europe) areas, as well as in one resistant African strain of *A. gambiae*. Our identification of this mutation may pave the way for designing new insecticides.

Acetylcholinesterase terminates synaptic transmission by hydrolysing the neurotransmitter acetylcholine; its inactivation by insecticides leads to paralysis and death. Mosquitoes, however, show widespread and strong resistance to this type of insecticide. They have two genes that encode different isoforms of acetylcholinesterase: *ace-1*, which has no homologue in the fruitfly *Drosophila melanogaster* and is closely linked to resistance in *C. pipiens*; and *ace-2*, a homologue of the unique *Drosophila* *ace* gene<sup>2</sup>. The generally mild insensitivity of acetylcholinesterase-2 in *D. melanogaster* is due to the combined weak effect of several mutations<sup>3</sup>.

To identify mutations involved in resistance in mosquitoes, we determined the complete *ace-1* messenger RNA coding sequence of two *Culex pipiens* strains: one susceptible and one resistant (results not shown). *C. pipiens ace-1* encodes a putative 702-amino-acid protein, which is 81% identical to its *A. gambiae* homologue and 39% identical to *D. melanogaster* acetylcholinesterase-2. Complementary DNAs from the susceptible and resistant strains differ at 27 nucleotide positions, only one of which generates an amino-acid substitution: the GGC (glycine) codon at position 119, according to the nomenclature for *Torpedo* acetylcholinesterase<sup>1</sup>, is replaced by an AGC (serine) codon in resistant mosquitoes (mutation G119S).

From three-dimensional modelling, we find that this mutated residue lies within the

active 'gorge' of the enzyme, close to the catalytic site and abutting the oxyanion hole (results not shown). To evaluate the biochemical effect of the mutation *in vitro*, we assayed the catalytic properties and insecticidal sensitivity of wild-type and mutant recombinant acetylcholinesterase-1 that was expressed in S2 *Drosophila* cells. The G119S mutant showed the same insensitivity to Propoxur insecticide as resistant-strain acetylcholinesterase-1 (Fig. 1). A single mutation in *ace-1* must therefore be responsible for the insensitivity of the enzyme.

To determine whether the G119S mutation is present in other *C. pipiens* strains with insensitive acetylcholinesterase, we sequenced exon 3 of *ace-1* in several resistant and susceptible strains derived either from the temperate or the tropical/subtropical form of the *C. pipiens* species complex (*C. p. pipiens* and *C. p. quinquefasciatus*, respectively). All of the resistant strains carried the G119S substitution, regardless of their origin. Moreover, although 23 nucleotides were polymorphic, a unique haplotype was found to be associated with the resistance within each subspecies (see supplementary information). This indicates that the same G119S mutation has occurred independently at least twice in *C. pipiens*, once in each subspecies.

We also investigated the recent emergence of insensitive acetylcholinesterase in the main African malaria vector *Anopheles gambiae*<sup>4</sup>, with the use of the *ace-1* genomic sequences of a resistant (YAO) and a susceptible (KISUMU) strain. The coding sequences differed at 18 nucleotide positions, two of them being non-synonymous. In the YAO strain, one mutation that resulted in the replacement of a valine residue by alanine in the amino-terminal region has no equivalent in *Torpedo* acetylcholinesterase and did not seem to affect the enzyme's catalytic properties (results not shown). The

other was the same G119S substitution as in *C. pipiens* (results not shown), indicating that this single point mutation has occurred independently at least three times in the *ace-1* gene: twice in the *C. pipiens* complex and once in *A. gambiae*.

The discovery of the *ace-1* mutation that is responsible for insecticide resistance in mosquitoes opens the way to new strategies for pest management. The development of new insecticides that can specifically inhibit the G119S mutant form of acetylcholinesterase-1 will be crucial in overcoming the spread of resistance.

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COMMUNICATIONS ARISING

Nitrogen storage

## UV-B radiation and soil microbial communities

Soil microorganisms regulate the supply of nitrogen to plants and so are important controllers of plant productivity and ecosystem carbon sequestration. Johnson *et al.*<sup>1</sup> report that exposure of a subarctic heath ecosystem to increased ultraviolet-B (UV-B) irradiation causes a drastic decline in the mass ratio of C:N in soil microorganisms, which would increase the amount of nitrogen stored in the microbial biomass and possibly alter the availability of nitrogen to plants. However, we argue that some of the authors' microbial C:N data are unrealistic, possibly because of an artefact of the technique used to measure microbial carbon and nitrogen concentrations. As a result, there is little reason to suppose that increased exposure of ecosystems to UV-B radiation will influence microbial nitrogen storage, plant nitrogen availability or rates of carbon sequestration.

Johnson *et al.* calculated an average microbial C:N ratio of 36.2 in control plots,